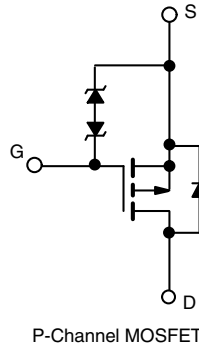
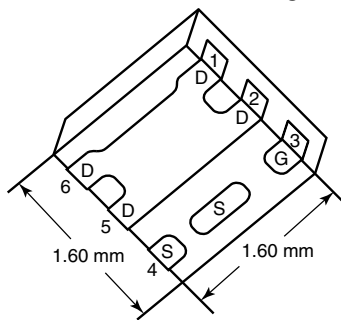




## P-Channel 12-V (D-S) MOSFET

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω) Max.	I <sub>D</sub> (A)	Q <sub>g</sub> (Typ.)
- 12	0.0255 at V <sub>GS</sub> = - 4.5 V	- g <sup>a</sup>	13.4 nC
	0.0280 at V <sub>GS</sub> = - 3.7 V	- g <sup>a</sup>	
	0.0360 at V <sub>GS</sub> = - 2.5 V	- g <sup>a</sup>	
	0.0600 at V <sub>GS</sub> = - 1.8 V	- g <sup>a</sup>	
	0.1150 at V <sub>GS</sub> = - 1.5 V	- 2	

PowerPAK SC-75-6L-Single



Ordering Information:  
SiB441EDK-T1-GE3 (Lead (Pb)-free and Halogen-free)

### FEATURES

- TrenchFET<sup>®</sup> Power MOSFET
- Thermally Enhanced PowerPAK<sup>®</sup> SC-75 Package
  - Small Footprint Area
  - Low On-Resistance
- Typical ESD Performance 2500 V
- 100 % R<sub>g</sub> Tested
- Material categorization: For definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

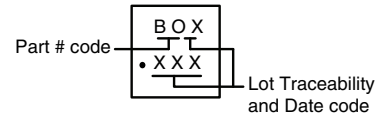


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### APPLICATIONS

- Portable Devices such as Smart Phones, Tablet PCs and Mobile Computing
  - Battery Switch
  - Load Switch
  - Power Management

### Marking Code



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)			
Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	- 12	V
Gate-Source Voltage	V <sub>GS</sub>	± 8	V
Continuous Drain Current (T <sub>J</sub> = 150 °C)	I <sub>D</sub>	T <sub>C</sub> = 25 °C	- g <sup>a</sup>
		T <sub>C</sub> = 70 °C	- g <sup>a</sup>
		T <sub>A</sub> = 25 °C	- 8.3 <sup>b, c</sup>
		T <sub>A</sub> = 70 °C	- 6.6 <sup>b, c</sup>
Pulsed Drain Current (t = 300 μs)	I <sub>DM</sub>	- 40	A
Continuous Source-Drain Diode Current	I <sub>S</sub>	T <sub>C</sub> = 25 °C	- g <sup>a</sup>
		T <sub>A</sub> = 25 °C	- 2 <sup>b, c</sup>
Maximum Power Dissipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	13
		T <sub>C</sub> = 70 °C	8.4
		T <sub>A</sub> = 25 °C	2.4 <sup>b, c</sup>
		T <sub>A</sub> = 70 °C	1.6 <sup>b, c</sup>
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C
Soldering Recommendations (Peak Temperature) <sup>d, e</sup>		260	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient <sup>b, f</sup>	t ≤ 5 s	R <sub>thJA</sub>	41	51	°C/W
Maximum Junction-to-Case (Drain)	Steady State	R <sub>thJC</sub>	7.5	9.5	

Notes:

- Package limited.
- Surface mounted on 1" x 1" FR4 board.
- t = 5 s.
- See solder profile ([www.vishay.com/doc?73257](http://www.vishay.com/doc?73257)). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.
- Maximum under steady state conditions is 105 °C/W.

SPECIFICATIONS ( $T_J = 25\text{ }^\circ\text{C}$ , unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{DS}$	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	-12			V
$V_{DS}$ Temperature Coefficient	$\Delta V_{DS}/T_J$	$I_D = -250\text{ }\mu\text{A}$		-5		mV/ $^\circ\text{C}$
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			2.7		
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	-0.4		-0.9	V
Gate-Source Leakage	$I_{GSS}$	$V_{DS} = 0\text{ V}, V_{GS} = \pm 8\text{ V}$			$\pm 4$	$\mu\text{A}$
		$V_{DS} = 0\text{ V}, V_{GS} = \pm 4.5\text{ V}$			$\pm 1$	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -12\text{ V}, V_{GS} = 0\text{ V}$			-1	
		$V_{DS} = -12\text{ V}, V_{GS} = 0\text{ V}, T_J = 55\text{ }^\circ\text{C}$			-10	
On-State Drain Current <sup>a</sup>	$I_{D(on)}$	$V_{DS} \leq -5\text{ V}, V_{GS} = -4.5\text{ V}$	-15			A
Drain-Source On-State Resistance <sup>a</sup>	$R_{DS(on)}$	$V_{GS} = -4.5\text{ V}, I_D = -4\text{ A}$		0.0210	0.0255	$\Omega$
		$V_{GS} = -3.7\text{ V}, I_D = -4\text{ A}$		0.0230	0.0280	
		$V_{GS} = -2.5\text{ V}, I_D = -2\text{ A}$		0.0290	0.0360	
		$V_{GS} = -1.8\text{ V}, I_D = -2\text{ A}$		0.0420	0.0600	
		$V_{GS} = -1.5\text{ V}, I_D = -0.5\text{ A}$		0.0570	0.1150	
Forward Transconductance <sup>a</sup>	$g_{fs}$	$V_{DS} = -6\text{ V}, I_D = -4\text{ A}$		17		S
<b>Dynamic<sup>b</sup></b>						
Input Capacitance	$C_{iss}$	$V_{DS} = -6\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		1180		pF
Output Capacitance	$C_{oss}$			265		
Reverse Transfer Capacitance	$C_{rss}$			250		
Total Gate Charge	$Q_g$	$V_{DS} = -6\text{ V}, V_{GS} = -8\text{ V}, I_D = -2.1\text{ A}$		22.1	33	nC
			$V_{DS} = -6\text{ V}, V_{GS} = -4.5\text{ V}, I_D = -2.1\text{ A}$		13.4	
$Q_{gs}$		1.6				
$Q_{gd}$		3.4				
Gate Resistance	$R_g$	$f = 1\text{ MHz}$	2.2	11	22	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -6\text{ V}, R_L = 2.7\text{ }\Omega$ $I_D \cong -2.2\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 1\text{ }\Omega$		22	45	ns
Rise Time	$t_r$			42	85	
Turn-Off Delay Time	$t_{d(off)}$			60	120	
Fall Time	$t_f$			50	100	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -6\text{ V}, R_L = 2.7\text{ }\Omega$ $I_D \cong -2.2\text{ A}, V_{GEN} = -8\text{ V}, R_g = 1\text{ }\Omega$		7	15	
Rise Time	$t_r$			10	20	
Turn-Off Delay Time	$t_{d(off)}$			60	120	
Fall Time	$t_f$			52	100	
<b>Drain-Source Body Diode Characteristics</b>						
Continuous Source-Drain Diode Current	$I_S$	$T_C = 25\text{ }^\circ\text{C}$			-9	A
Pulse Diode Forward Current	$I_{SM}$				-40	
Body Diode Voltage	$V_{SD}$	$I_S = -2.2\text{ A}, V_{GS} = 0\text{ V}$		-0.85	-1.2	V
Body Diode Reverse Recovery Time	$t_{rr}$	$I_F = -2.2\text{ A}, di/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^\circ\text{C}$		30	60	ns
Body Diode Reverse Recovery Charge	$Q_{rr}$			12	25	nC
Reverse Recovery Fall Time	$t_a$			9		ns
Reverse Recovery Rise Time	$t_b$			11		

Notes:

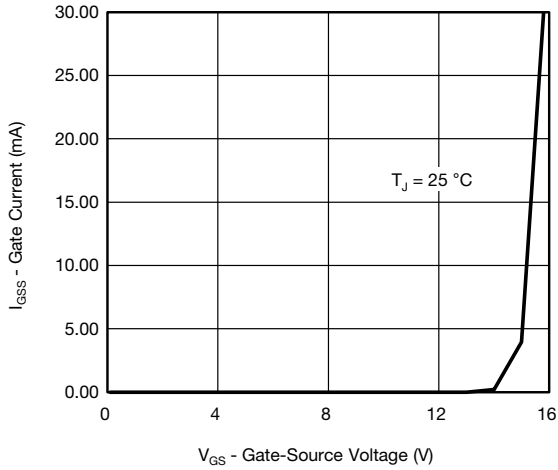
a. Pulse test; pulse width  $\leq 300\text{ }\mu\text{s}$ , duty cycle  $\leq 2\%$ .

b. Guaranteed by design, not subject to production testing.

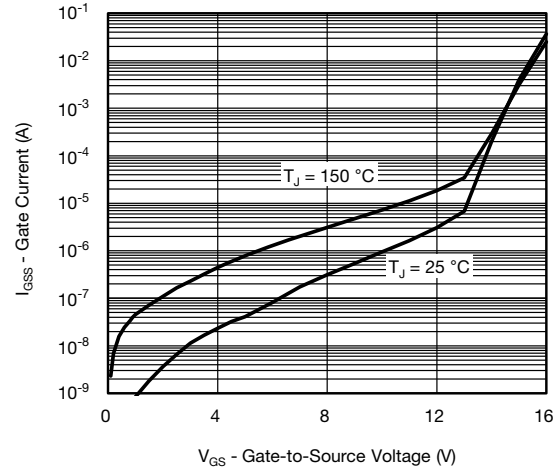
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



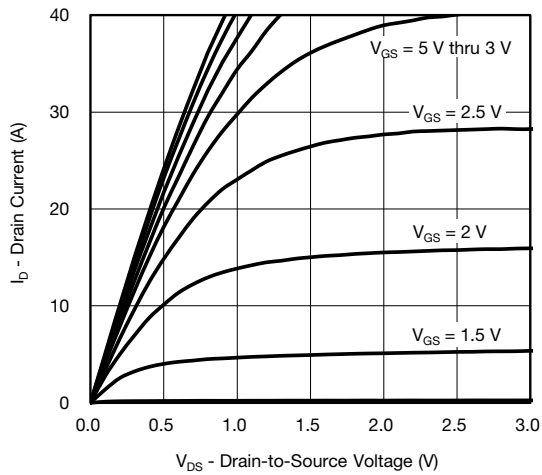
**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)



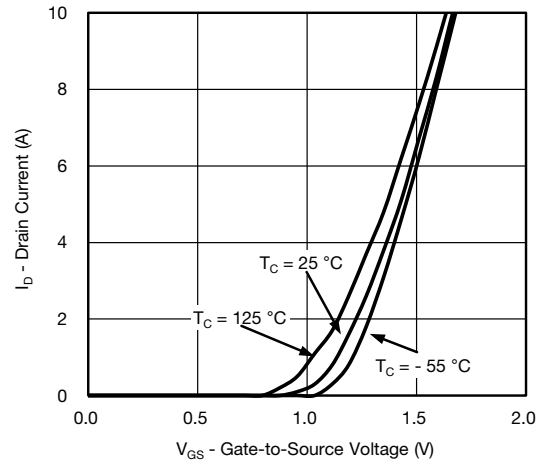
**Gate Current vs. Gate-Source Voltage**



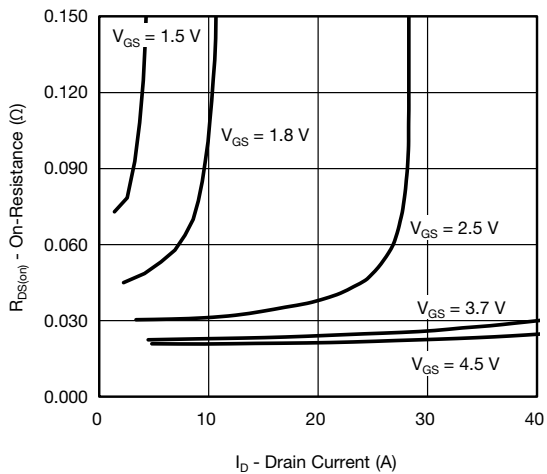
**Gate Current vs. Gate-Source Voltage**



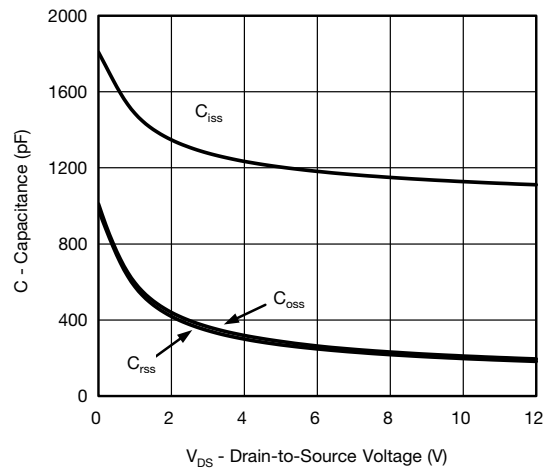
**Output Characteristics**



**Transfer Characteristics**



**On-Resistance vs. Drain Current**



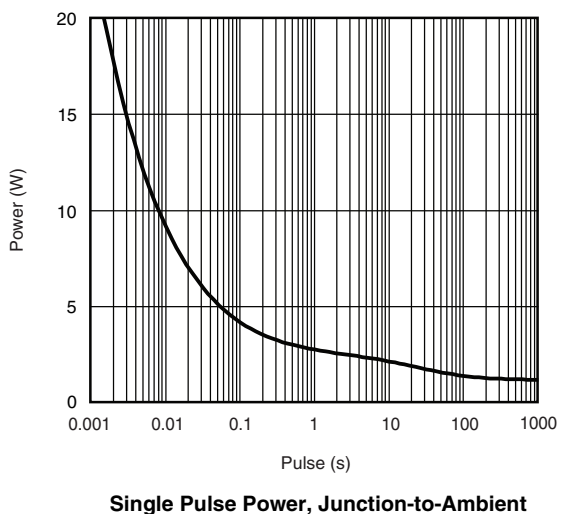
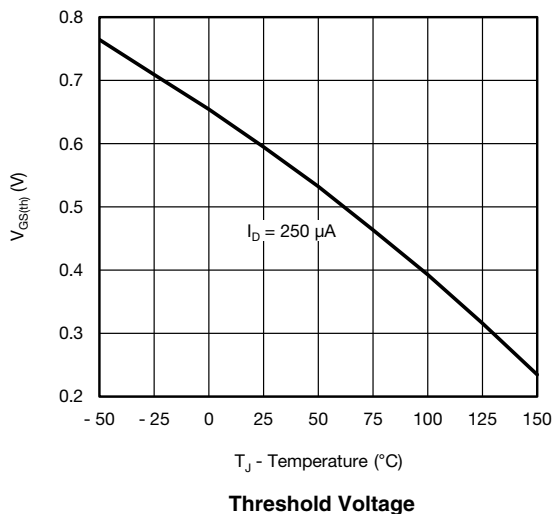
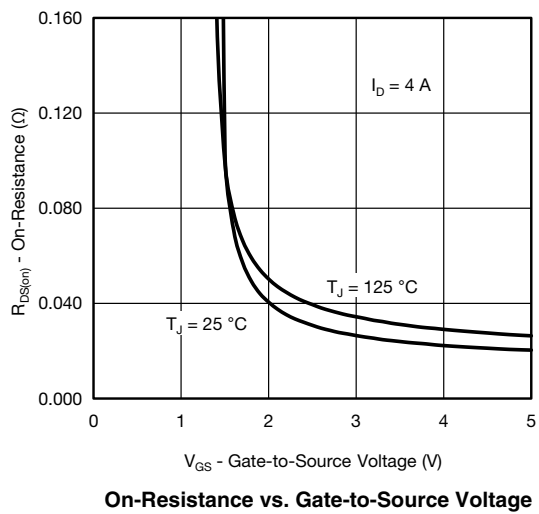
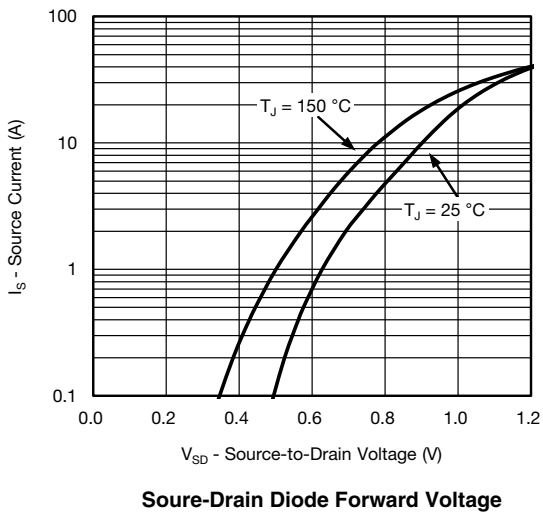
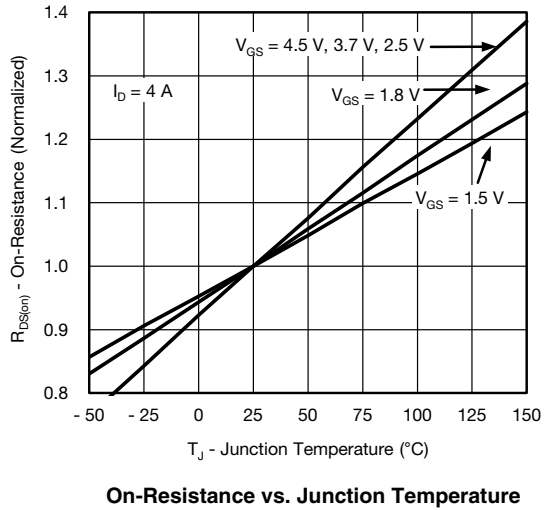
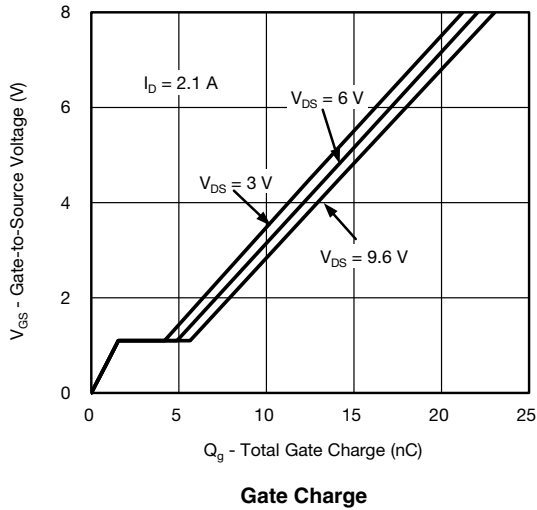
**Capacitance**

# SiB441EDK

Vishay Siliconix

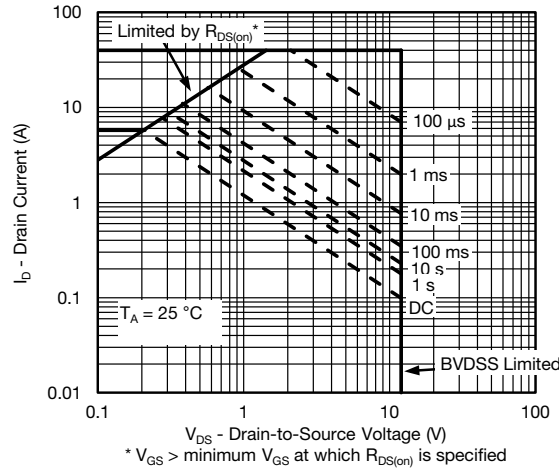


## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

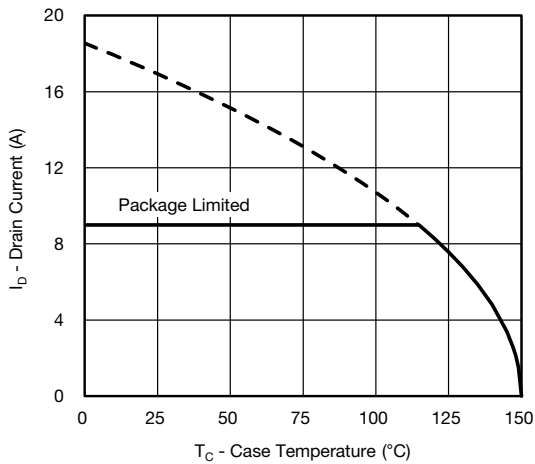




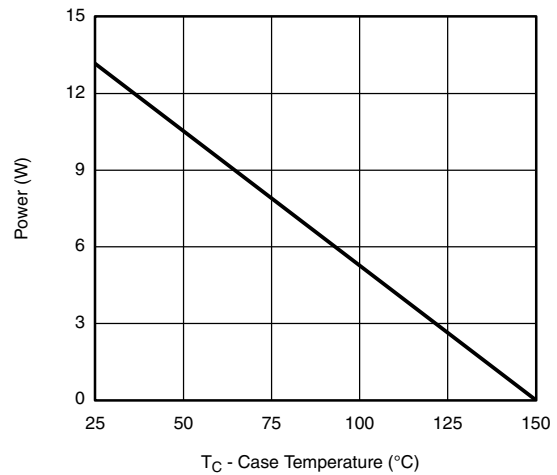
**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)



**Safe Operating Area, Junction-to-Ambient**



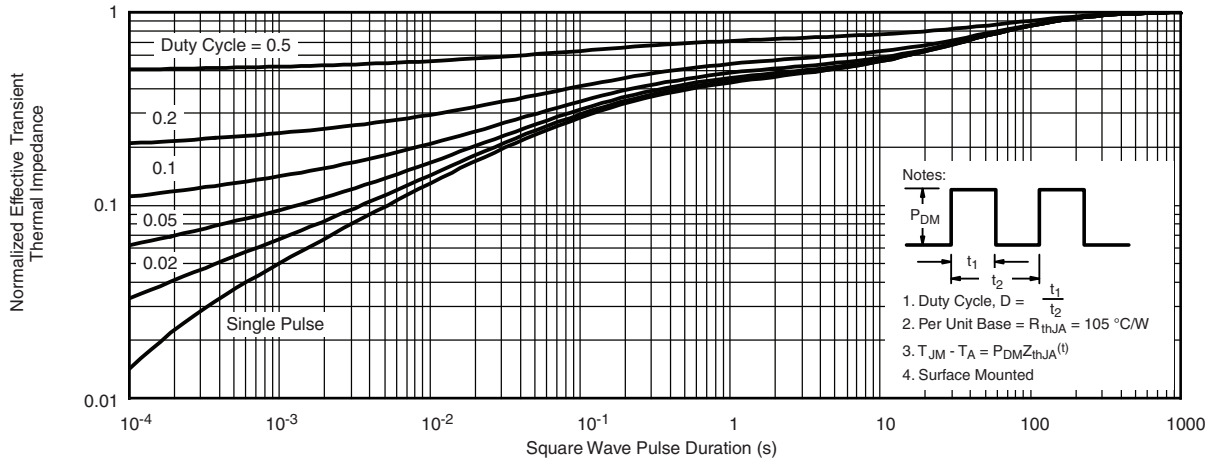
**Current Derating\***



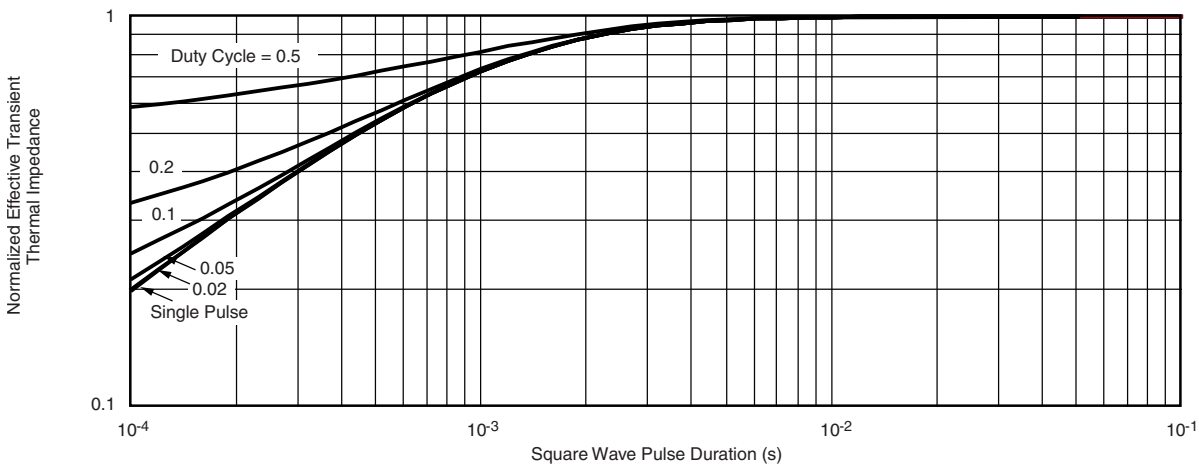
**Power Derating**

\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

**TYPICAL CHARACTERISTICS** (25 °C, unless otherwise noted)



**Normalized Thermal Transient Impedance, Junction-to-Ambient**

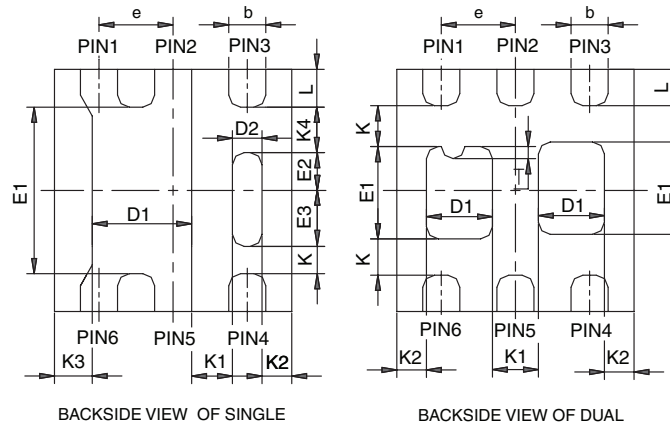


**Normalized Thermal Transient Impedance, Junction-to-Case**

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see [www.vishay.com/ppg?62821](http://www.vishay.com/ppg?62821).

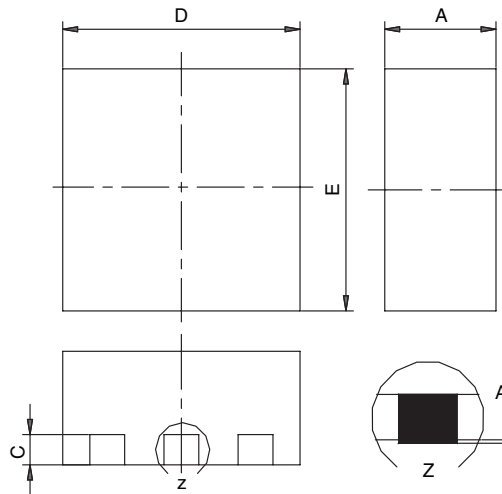


PowerPAK® SC75-6L



BACKSIDE VIEW OF SINGLE

BACKSIDE VIEW OF DUAL



Notes:

- 1. All dimensions are in millimeters
- 2. Package outline exclusive of mold flash and metal burr
- 3. Package outline inclusive of plating

DIM	SINGLE PAD						DUAL PAD					
	MILLIMETERS			INCHES			MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max	Min	Nom	Max
A	0.675	0.75	0.80	0.027	0.030	0.032	0.675	0.75	0.80	0.027	0.030	0.032
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002
b	0.18	0.25	0.33	0.007	0.010	0.013	0.18	0.25	0.33	0.007	0.010	0.013
C	0.15	0.20	0.25	0.006	0.008	0.010	0.15	0.20	0.25	0.006	0.008	0.010
D	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
D1	0.57	0.67	0.77	0.022	0.026	0.030	0.34	0.44	0.54	0.013	0.017	0.021
D2	0.10	0.20	0.30	0.004	0.008	0.012						
E	1.53	1.60	1.70	0.060	0.063	0.067	1.53	1.60	1.70	0.060	0.063	0.067
E1	1.00	1.10	1.20	0.039	0.043	0.047	0.51	0.61	0.71	0.020	0.024	0.028
E2	0.20	0.25	0.30	0.008	0.010	0.012						
E3	0.32	0.37	0.42	0.013	0.015	0.017						
e	0.50 BSC			0.020 BSC			0.50 BSC			0.020 BSC		
K	0.180 TYP			0.007 TYP			0.245 TYP			0.010 TYP		
K1	0.275 TYP			0.011 TYP			0.320 TYP			0.013 TYP		
K2	0.200 TYP			0.008 TYP			0.200 BSC			0.008 TYP		
K3	0.255 TYP			0.010 TYP								
K4	0.300 TYP			0.012 TYP								
L	0.15	0.25	0.35	0.006	0.010	0.014	0.15	0.25	0.35	0.006	0.010	0.014
T							0.03	0.08	0.13	0.001	0.003	0.005

ECN: C-07431 – Rev. C, 06-Aug-07  
DWG: 5935

## RECOMMENDED PAD LAYOUT FOR PowerPAK® SC75-6L Single



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